

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX574F, TC74LCX574FK

Low-Voltage Octal D-Type Flip-Flop with 5-V Tolerant Inputs and Outputs

The TC74LCX574 is a high-performance CMOS octal D-type flip-flop. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

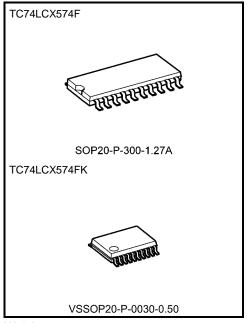
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high-impedance state.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: VCC = 1.65 to 3.6 V
- High-speed operation: $t_{pd} = 8.5 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: >±500 mA
- Available in JEITA SOP, VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 574 type



Weight

SOP20-P-300-1.27A : 0.22 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Note: The Electrical Characteristics of $V_{\rm CC}$ = 1.8 \pm 0.15 V is only applicable for products which manufactured from January 2009 onward.

Start of commercial production 1994-10

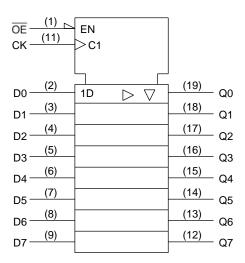
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Pin Assignment (top view)

$\overline{\mathsf{OE}}$ 20 Vcc D0 Q0 2 19 D1 3 Q1 Q2 D2 Q3 D3 5 D4 6 Q4 D5 7 Q5 Q6 D6 8 D7 9 Q7 GND 10 CK

IEC Logic Symbol



Truth Table

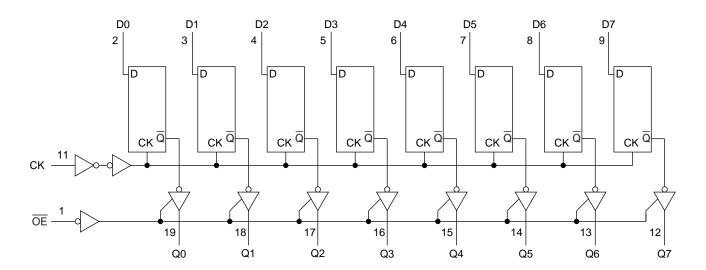
	Outputo		
ŌĒ	CK	D	Outputs
Н	Х	Х	Z
L	\neg	Х	Qn
L		L	L
L		Н	Н

X: Don't care

Z: High impedance

Qn: No change

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	Vout	-0.5 to V _{CC} $+ 0.5$ (Note 3)	V
Input diode current	lıĸ	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC Vcc/ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Dower gunnly voltage	Voc	1.65 to 3.6	V	
Power supply voltage	Vcc	1.5 to 3.6 (Note 2)	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	Vout	0 to 5.5 (Note 3)	V	
Output voltage	Vout	0 to V _{CC} (Note 4)	V	
Output current	lou/lou	±24 (Note 5)	mA	
Output current	IOH/IOL	±12 (Note 6)	IIIA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: VCC = 3.0 to 3.6 V

Note 6: VCC = 2.7 to 3.0 V

Note 7: VIN = 0.8 to 2.0 V, VCC = 3.0 V



Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characteris	stics	Symbol	Test Condition Vcc (V)		Min	Max	Unit		
					1.65 to 2.3	V _{CC} × 0.9	_		
	H-level	VIH	_		2.3 to 2.7	1.7	_		
					2.7 to 3.6	2.0	_	V	
Input voltage					1.65 to 2.3	_	Vcc × 0.1		
	L-level	VIL	_	-	2.3 to 2.7	_	0.7		
					2.7 to 3.6	_	0.8		
				IOH = -100 μA	1.65 to 3.6	Vcc-0.2	_		
				I _{OH} = -4 mA	1.65	1.05	_		
	H-level	Vari	VIN = VIH or VIL	IOH = -8 mA	2.3	1.7	_	V	
	H-level	Voн	VIN = VIH OF VIL	IOH = -12 mA	2.7	2.2	_		
				I _{OH} = -18 mA	3.0	2.4	_		
Output voltage				IOH = -24 mA	3.0	2.2			
Output voltage			VIN = VIH or VIL	I _{OL} = 100 μA	1.65 to 3.6	_	0.2		
				I _{OL} = 4 mA	1.65		0.45		
	L-level	Vol		IOL = 8 mA	2.3		0.7		
	L-level	VOL		IOL = 12 mA	2.7	_	0.4		
					I _{OL} = 16 mA	3.0		0.4]
					IOL = 24 mA	3.0		0.55	
Input leakage current		l _{IN}	V _{IN} = 0 to 5.5 V		1.65 to 3.6	_	±5.0	μΑ	
3-state output off-state	current	loz	VIN = VIH or VIL VOUT = 0 to 5.5 V		1.65 to 3.6		±5.0	μА	
Power off leakage curr	ent	loff	$V_{IN}/V_{OUT} = 5.5 V$		0	— 10.0		μА	
Octobrond something		Icc	VIN = VCC or GND		1.65 to 3.6		10.0		
Quiescent supply curre	Quiescent supply current		$V_{IN}/V_{OUT} = 3.6 to$	V _{IN} /V _{OUT} = 3.6 to 5.5 V		_	±10.0	μΑ	
Increase in I _{CC} per inp	ut	Δlcc	V _{IH} = V _{CC} - 0.6 V (per 1 input)		2.7 to 3.6	_	500		



AC Characteristics (Ta = -40 to 85°C)

Characteristics	Test Condition		Min Max		Unit	
Characteristics	Symbol	rest Condition	V _{CC} (V)	IVIII I	IVIAX	Offic
Marian de la Company			1.8 ± 0.15	50		MHz
	f _{max}	Figure 1, Figure 2	2.5 ± 0.2	100	_	
Maximum clock frequency	ımax	rigule 1, rigule 2	2.7	100	_	
			3.3 ± 0.3	150	_	
			1.8 ± 0.15	_	30.0	
Propagation delay time	tpLH	Figure 1, Figure 2	2.5 ± 0.2	_	10.5	no
(CK-Q)	tpHL	rigule 1, rigule 2	2.7	_	9.5	ns
			3.3 ± 0.3	1.5	8.5	
			1.8 ± 0.15	_	34.0	
Outroit and blatima	tpZL	Figure 4 Figure 2	2.5 ± 0.2	_	17.0	
Output enable time	t _p ZH	Figure 1, Figure 3	2.7		9.5	ns
			3.3 ± 0.3	1.5	8.5	
	^t pLZ ^t pHZ	Figure 1, Figure 3	1.8 ± 0.15	_	28.0	ns
			2.5 ± 0.2	_	14.0	
Output disable time			2.7		7.0	
			3.3 ± 0.3	1.5	6.5	
		Figure 1, Figure 2	1.8 ± 0.15	10.0	_	ns
Minimum pulse width	t _W (H) t _W (L)		2.5 ± 0.2	5.0	_	
(CK)			2.7	3.3	_	
			3.3 ± 0.3	3.3	_	
			1.8 ± 0.15	10.0	_	
Minimum out up time			2.5 ± 0.2	5.0		ns
Minimum set-up time	t _S	Figure 1, Figure 2	2.7	2.5	_	
			3.3 ± 0.3	2.5	_	
		Figure 1, Figure 2	1.8 ± 0.15	1.5		
Minimum hold time	+,		2.5 ± 0.2	1.5	_	ns
	th		2.7	1.5		
			3.3 ± 0.3	1.5	_	
Output to output skew	t _{osLH}	(Note)	2.7		_	ne
Salpat to output skew	t _{osHL}	(Note)	3.3 ± 0.3	_	1.0	ns

Note: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)



Dynamic Switching Characteristics (Ta= 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

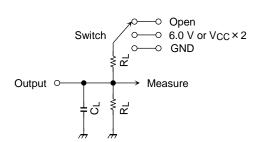
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	CIN	_	3.3	7	pF
Output capacitance	Соит	_	3.3	8	pF
Power dissipation capacitance	CPD	f _{IN} = 10 MHz (Note)	3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/8 (per bit)

AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t t	6.0 V	@ Vcc =3.3±0.3V @ Vcc =2.7V	
t _{pLZ} , t _{pZL}	Vcc×2 @ Vcc =2.5±0.2V @ Vcc =1.8±0.15		
t _{pHZ} , t _{pZH}	GND		

Figure 1



AC Waveform

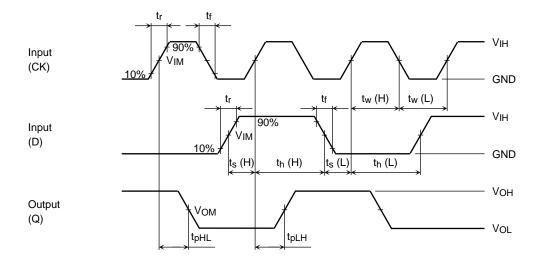


Figure 2 t_{pLH}, t_{pHL}, t_w, t_s, t_h

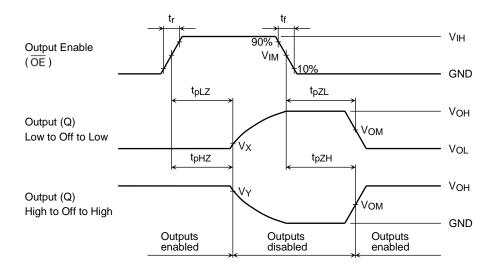


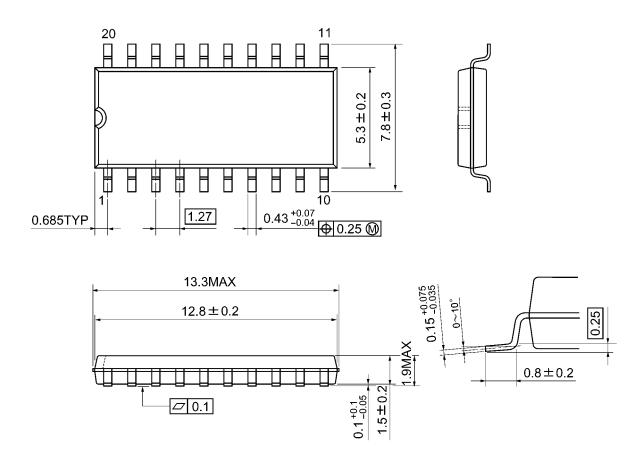
Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

		Vcc				
	Symbol	$3.3 \pm 0.3 \ \textrm{V}$ $2.7 \ \textrm{V}$	$2.5\pm0.2~\textrm{V}$	1.8 ± 0.15 V		
Input	VIH	2.7 V	Vcc	Vcc		
	VIM	1.5 V	V _{CC} /2	V _{CC} /2		
	t _r , t _f	2.5 ns	2.0 ns	2.0 ns		
Output	VoM	1.5 V	V _{OH} /2	V _{OH} /2		
	Vx	V _{OL} +0.3 V	V _{OL} +0.15 V	V _{OL} +0.15 V		
	VY	V _{OH} -0.3 V	V _{OH} -0.15 V	V _{OH} -0.15 V		
Load	CL	50 pF	30 pF	30 pF		
	RL	500 Ω	500 Ω	1 kΩ		



Package Dimensions

SOP20-P-300-1.27A Unit: mm

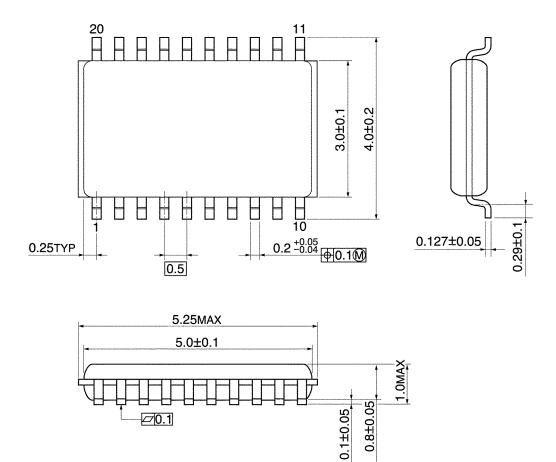


Weight: 0.22 g (typ.)



Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



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